AEROPHYSICS
HAL WILLIAMS
130/314

OPERATING INSTRUCTIONS

FOR

MILLIVAC

VS68 A

SUCCESS OR FAILURE OF OPERATING AN INSTRUMENT SATISFACTORILY OFTEN DEPENDS UPON WHETHER INSTRUCTIONS HAVE BEEN READ OR NOT.

MILLIVAC INSTRUMENTS INC.

BOX 997, SCHENECTADY, N.Y.

OPERATING INSTRUCTIONS

FOR

HUSHED TRANSISTOR PRE-AMPLIFIER TYPE VS-68A

The VS-68A Hushed Transistor Pre-Amplifier is a high impedance version of the well known VS-64A Pre-Amplifier.

The two amplifiers are identical with the exception of the input stage. A brief inspection of drawing T-6003, attached, will show that transistor t1 has been replaced by two 12 EK 6 vacuum tubes connected in parallel in a similar cathode follower circuit. The normal high impedance of the vacuum tubes plus the degeneration of the cathode follower circuit makes the input impedance of 10 meg. ohms easily obtainable.

Transistors as emitter followers are very efficient, usually 98 to 99%. Vacuum tubes however are less efficient. To make up for this deficiency, the gain of the pre-amplifier must be increased. This is accomplished by adding an extra contact on the input impedance selection switch which connects a shunting resistor R55 in parallel with feed-back resistor R9, when switched to the 10 meg. position.

One other change is made as a result of the use of vacuum tubes. The voltage at the cathodes of the tubes is positive, and this makes it necessary to reverse the polarity of the input condensor C2 (250MF, 6V).

The 2-12 EK 6 tubes in the cathode follower circuit get their filament and plate voltage from an external 12 volt storage battery.

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https://archive.org/details/manualsplus_11993

This battery is only necessary when using the amplifier in its 10 meg. input impedance position. Internal batteries provide all the power necessary to operate this amplifier in the 10K position.

For a comparision of signal to noise ratios and other specifications refer to Bulletin M 6003 at the end of this book.

ENGINEERING DEPARTMENT
MILLIVAC INSTRUMENTS
DIV. OF COHU ELECTRONICS, INC.
SCHENECTADY, NEW YORK

VS-68 A PARTS LIST

Resistors

R1-10K
R2-500*
R3-500*
R4-1 Meg Cont.
R5-100K
R6-10K
R7-6K*
R8-2K*
R9-5*
R10-5K Cont.
R11-2K*
R12-2K*
R13-10K
R14-375*
R15-51
R16-1 Meg Cont.
R17-100K
R18-6K*
R19-10K
R20-2K*
R21-10*
R22-2K*
R23-5K Cont.
R24-2K*
R25-10K
R26-375*
R27-270 ADJ
R28-110
R29-34.5
R30-11
R31-5.1
R32-200
R33-510K
R34-7.5K
R35-10K
R36-4.7K
R37-8.2K
R38-7.5K
R39-11K
R40-11K
R41-11K
R42-6.2K
R43-6.2K
R44-6.2K
R45-6.2K
R46-510K
R47-10K
R48-100K
R49-2.4K ADJ
R50-100K
R51-100K
R52-3K
R53-10K
R54-10 meg
R55-10

Condensers

C1-2MF
C2-250MF,6V
C3-250MF,6V
C4-#303 Trimmer
C5-2000MMF
C6-250MF,6V
C7-1000MF,6V
C8-250MF,6V
C9-#303 Trimmer
C10-#303 Trimmer
C11-3000MMF
C12-250MF,6V
C13-250MF,6V
C14-#303 Trimmer
C15-.1MF
C16-.2MF
C17-.01MF
C18-.004 Hicap
C19-.002 Hicap
C20-.001MF
C21-500MMF
C22-220MMF
C23-100MMF
C24-50MMF
C25-
C26-
C27-1000MMF
C28-1200MMF
C29-1500MMF
C30-2000MMF
C31-3000MMF
C32-5000MMF
C33-.02 Disc
C34-.04MF,200V
C35-.25MF,200V
C36-1MF,200V
C37-8MF,250V
C38-100MF,50V
C39-250MF,6V
C40-250MF,6V
C41-250MF,6V
C42-
C43-8MF,250V

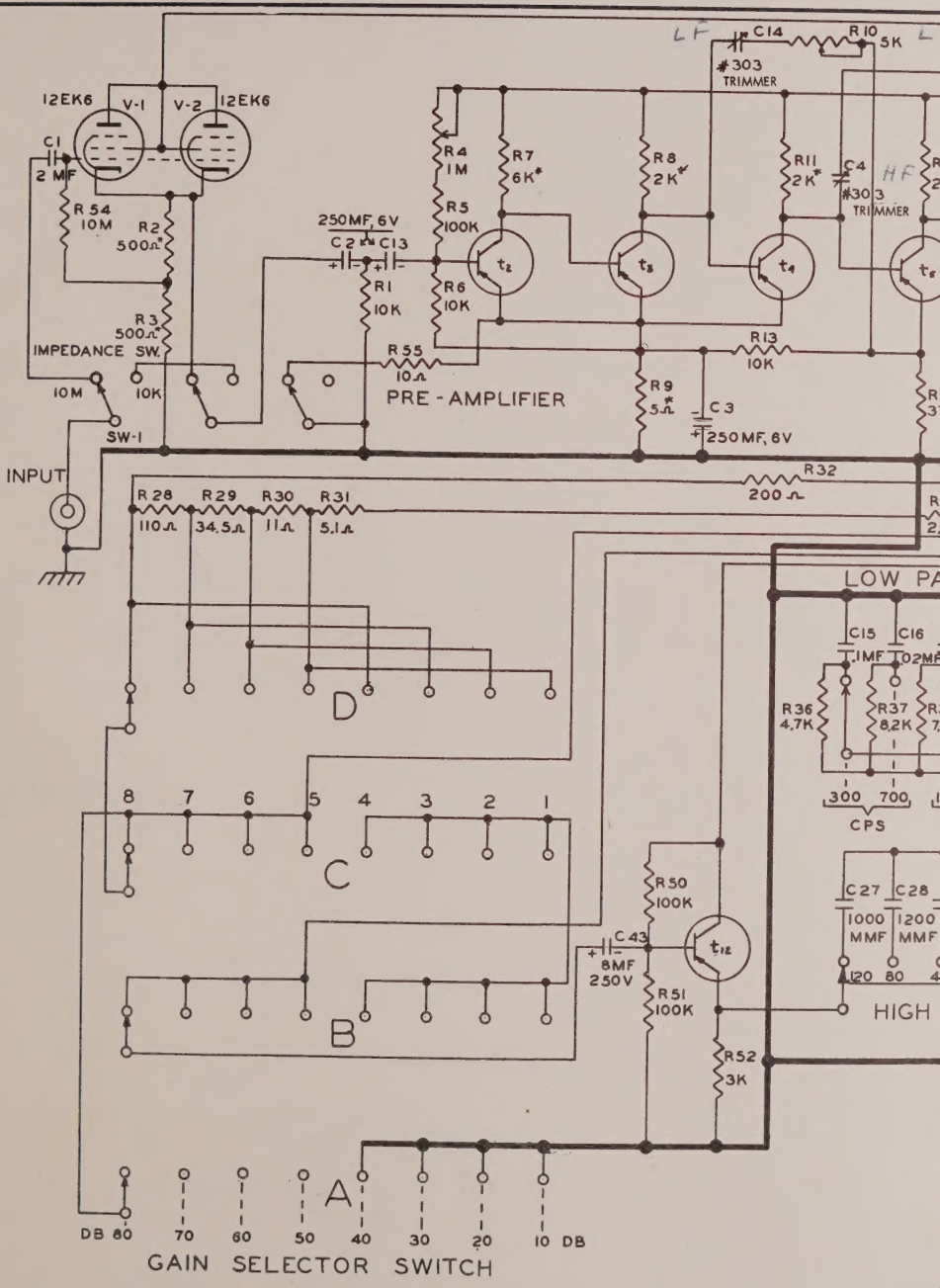
Transistors

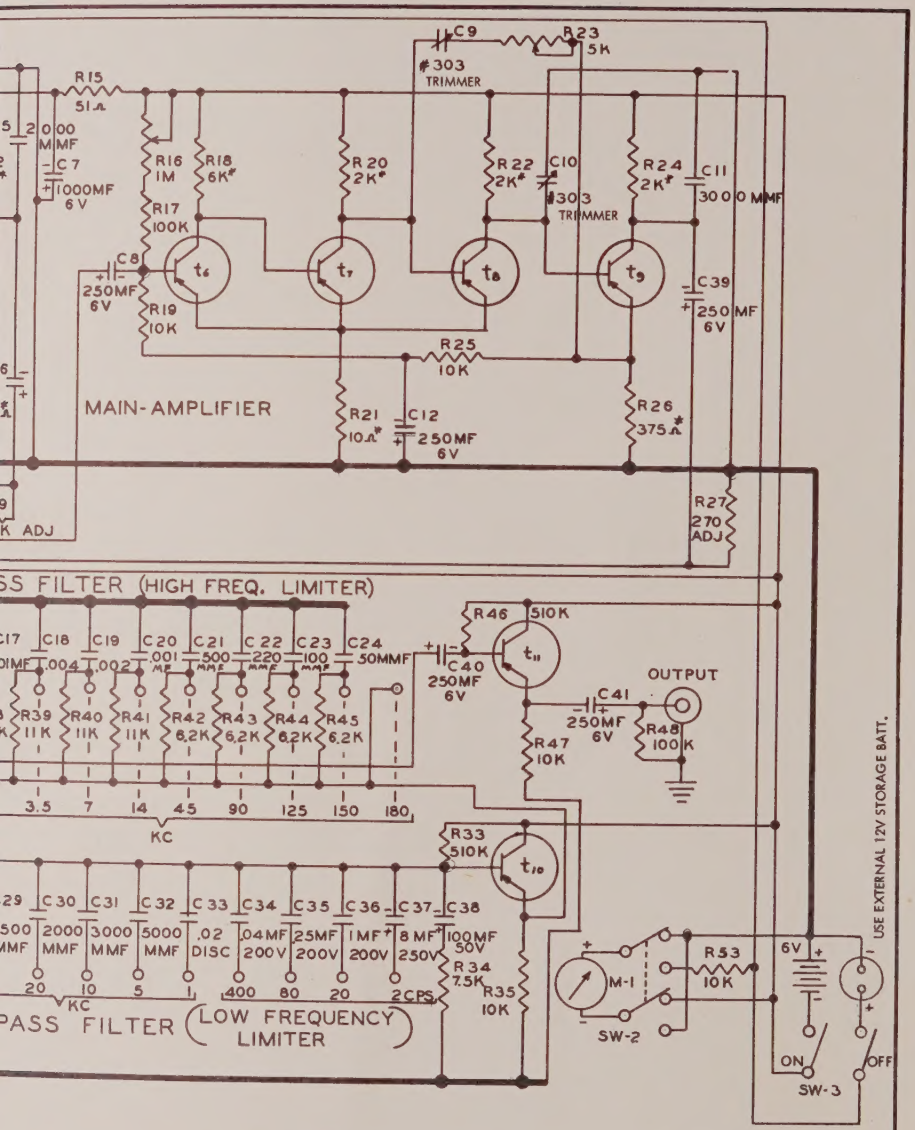
T2-2N414
T3-2N189
T4-2N189
T5-2N189
T6-2N414
T7-2N189
T8-2N189
T9-2N189
T10-2N189
T11-2N189
T12-2N189

Tubes

V1-12EK6
V2-12EK6

20 Myr


12EK6
V-1
V-2
12EK6
C1
2 MF
R 54
10M
R2
500Ω
R3
500Ω
IMPEDANCE SW.
10M
10K
SW-1
INPUT
250MF, 6V
C2
C13
R1
10K
R4
1M
R5
100K
R6
10K
R7
6K*
R55
10Ω
PRE-AMPLIFIER
R8
2K*
R9
5Ω*
C3
250MF, 6V
R11
2K*
C4
#303
TRIMMER
C14
R10
5K
#303
TRIMMER
R13
10K
R32
200Ω
R28
110Ω
R29
34.5Ω
R30
11Ω
R31
5.1Ω
D
C
B
A
8
7
6
5
4
3
2
1
DB 80
70
60
50
40
30
20
10 DB
GAIN SELECTOR SWITCH
LOW PA
C15
.1MF
C16
.02MF
R36
4.7K
R37
8.2K
300
700
CPS
C27
1000
MMF
C28
1200
MMF
120
80
HIGH
R50
100K
C43
8MF
250V
R51
100K
R52
3K



TITLE	HIGH IMPEDANCE LOW NOISE AMPLIFIER	TYPE	V5-68A	REVISIONS
MILLIVAC INSTRUMENTS DIVISION OF COHU ELECTRONICS, INC. SCHENECTADY, NEW YORK				
DATE	DRAWN	APPROVED	DWG. NO.	
7-2-60	R. S. Smith		T 60,033	

MILLIVAC INSTRUMENTS

TYPE VS-68A

Low-Noise, High-Impedance Amplifier

ULTRA LOW NOISE

HIGH IMPEDANCE INPUT

HIGH GAIN
10-80DB

BATTERY OPERATED

VARIABLE BANDPASS

PORTABLE

DESCRIPTION OF VS-68A AMPLIFIER

The world record for freedom from electronic noise in amplifiers is, at present, held by the Millivac type VS-64A Hushed Transistor Amplifier. With it, noise measurements over a 10 kc passband show less than 150 milli-microvolts RMS, referred to the shorted input terminals. Such freedom from noise has never been obtained in vacuum tube amplifiers, and the present status of the art does not indicate that this will be the case in the foreseeable future. On the other hand the "hushed transistor" amplifier has definite limits in input impedance, usually 100 K (max.). By applying the hushing principle to a pair of input tubes, we obtain high input impedance (10 meg) with very low noise. By installing this input stage ahead of our hushed transistor amplifier, we accomplish the desired combination of high input impedance with excellent signal-to-noise ratio.

This amplifier contains most of the circuitry found in the VS-64A Hushed Transistor Amplifier, including its 10 K input circuit which generates only 150 muV RMS noise voltage if the input terminals are shorted. If higher impedance (10 meg) is desired, an impedance selector switch connects the low noise vacuum tube circuit to the input socket and noise voltage, referred to the shorted input terminals, increases to 1.4 uV RMS over a 10 kc pass-band. This noise voltage is substantially better than found in most vacuum tube amplifiers, yet inferior to the noise voltage of the 10 K hushed transistor circuit.

When connecting this amplifier to comparatively large source impedances, the advantage of a vacuum tube input circuit becomes apparent: 10 K is an approximate practical limit for source impedance in conjunction with the 10 K hushed transistor circuit. Noise voltage is then 4.2 uV RMS, referred to the 10 K source. When switching over to 10 meg input, the vacuum tube circuit reduces this noise voltage to 3.6 uV RMS, referred to the 10 K source. When increasing source impedance to 100 K, the noise voltage over the 10 KC pass-band becomes 11 uV, and with a 1 meg source, it is 20 uV. Narrower band width reduces noise voltage approximately in proportion with the root of bandwidth. In other words, with 100 cycle bandwidth, noise voltage is roughly one-tenth of the values mentioned for the 10 KC bandwidth.

The VS-68A has the same total frequency range (2 cps-180 KC) and the same upper and lower band pass limiting selector switches which the VS-64A has. Its gain is also 80 db, selectable in 10 db steps.

This amplifier uses a 12 V storage battery to energize the vacuum tubes. The VS-68A, in addition, uses two dry cell 6 V batteries which are also found in the VS-64A Hushed Transistor Amplifier. For use in the field, it may sometimes not be necessary to operate the VS-68A through its 10 meg input circuit. In this case, the external storage battery can be omitted and the amplifier will operate on its own internal 6 V dry cells.

SPECIFICATIONS

Gain: 10-80 db plus/minus 1 db, selectable 10 db steps.

Input Impedance: 10 K with transistors; 10 meg with tubes.

Frequency Response: 3 db down at 2 cps and at 180 KC.

Upper Bandpass Limits: 180, 150, 125, 90, 45, 14, 7, 3.5 and 1.5 KC; 700 and 300 cps.

Lower Bandpass Limits: 2, 20, 80 and 400 cps; 1, 5, 10, 20, 40, 80 and 120 KC.

Output Impedance: Less than 2 K.

Maximum Output: 100 mV R.M.S.

Distortion: 1% max. at 50 mV PTP, 2.5% at 100 mV PTP.

Noise (Bandpass of 10kC):

Input Resistance	10 K Transistor Input	10 meg Tube Input
Shorted Input	0.2 uV RMS	1.4 uV
500 ohms	0.8 uV (from text above)	1.6 uV
1 K	1.3 uV	1.7 uV
10 K	4.2 uV	3.6 uV
100 K	--	11 uV

Power Supply: Two Burgess F4P1, 6 V dry cells (supplied) and one 12 V storage battery (not supplied).

Physical Characteristics: Gray steel, hammertone finish case.

Height: 6-1/2", Width: 7", Depth (incl. rail): 12", Weight: 20 lbs.

Specifications subject to change without notice.

OPERATING INSTRUCTIONS

FOR

HUSHED TRANSISTOR PRE-AMPLIFIER TYPE VS-64A

Introduction: The VS-64A Hushed Transistor Pre-Amplifier is a highly sensitive pre-amplifier for oscilloscopes. It excels other amplifiers by having an exceptionally low noise voltage, referred to its input terminals. This noise voltage increases as the generator resistance, or source impedance to which the amplifier is connected, is increased. The relationship between noise voltage, referred to the input terminals, and generator resistance is shown on page 2 of bulletin M-6001 inserted at the end of this instruction book. Additional information concerning the VS-64A amplifier and complete performance specifications may also be found in this bulletin.

The amplifier can be operated with two different input impedances, 10 K and 100 K. The 10 K input impedance is obtained by feeding signals directly into the first amplifying transistor, which operates in a so-called "hushed" condition. The actual input impedance of this transistor is approximately 1 K, but it is increased through heavy negative feedback. The 100 K input impedance is obtained by connecting in series with the input circuit of the amplifier an emitter-follower which, by virtue of its comparatively high transconductance (25,000) and large emitter load resistance (6K), possesses such a high negative feedback ratio that the original 1 K impedance of the transistor is increased to 100 K.

Description of Operation: The amplifier is equipped with two interchangeable shielded clip leads, one for its input, and one for its output.

To make some preliminary tests for the purpose of verifying the proper functioning of the amplifier and getting acquainted with microvolt-level amplification, connect the amplifier's output to an oscilloscope having a sensitivity of at least 100 mV peak-to-peak for full screen deflection. The scope should be set for a 60 cps sweep rate and shouldbe synchronized by the power line. Do not synchronize the scope internally since a random sweep frequency would make it impossible to distinguish between accidental hum pick-up and amplifier noise. Some scopes are equipped with a 60 cps calibrator. In this case, the calibration signal should temporarily be used for the purpose of adjusting the sweep frequency and line sync until a single steady 60 cps wave appears on the screen.

Each amplifier is shipped with a 100,000/1 test divider consisting of a 1 meg and a 10 ohm resistor mounted in a well-shielded metal tube. This test divider should now be plugged into the input receptacle of the VS-64A amplifier and the shielded clip lead should then be connected to an audio frequency signal generator which delivers a 100 mV, 360 cps signal. Since the scope is being swept at a rate of 60 cps, six full waves will therefore appear on the screen. If they drift from left to right or in the opposite direction, this would indicate that the frequency calibration of the generator is not quite accurate and the six waves should be brought to a standstill by slightly changing the frequency

setting of the generator (not by making adjustments with the sweep or sync controls of the scope).

The gain selector switch of the VS-64A amplifier should be set to 80 DB and the input impedance selector should be turned to the 10 K position. The upper bandpass switch should be set to 180 KC, which is fully clockwise, and the lower bandpass switch should be turned to the 2 cps position, also fully clockwise.

Check the battery voltage on the voltmeter. It should be at least 5.4 V.

The voltage of the signal being fed into the amplifier should be monitored with a suitable VTVM. The output of the generator should be adjusted for 100 mV RMS at 360 cps. The 100,000/1 input divider reduces this voltage to 1 uV RMS.

Since the gain of the amplifier in the 80 DB position is approximately 10,000, it will put out a 10 mV RMS signal, equivalent to 28 mV peak-to-peak and therefore approximately 28% of full screen sensitivity of the scope if the sensitivity of the scope is 100 mV peak-to-peak and if it is turned up to its maximum sensitivity.

The six waves representing the 1 uV RMS signal being fed into the amplifier will exhibit a certain amount of noise (grass). With both bandpass switches turned up fully as described, the noise should be approximately 650 to 750 muV RMS, referred to the input. This is at least 20 DB less noise than a conventional vacuum tube amplifier would exhibit under identical conditions.

Noise can be reduced by cutting down the band width of the amplifier. The relationship between noise voltage, referred to the input terminals, and various positions of the upper and lower bandpass limiting switches is given in a table on page 2 of the bulletin M-6001 attached to the end of this instruction book. A few settings should be tried out. It should be noted that particularly when turning the upper bandpass switch down toward the low kilocycle region, most of the grass in the 1 uV signal trace will disappear.

In many cases a test of this kind will reveal the presence of a certain amount of hum appearing on the scope. It may be as high as 1 μV RMS, sometimes even more. The following causes for such hum pick-up have been found to be the most frequent ones:

(a) Location of the VS-64A amplifier in the immediate vicinity of a line-operated device such as a vacuum tube voltmeter, scope or signal generator, whose power transformer radiates a rather powerful hum-field which interferes with the VS-64A amplifier's input signal. Shifting the amplifier to a more remote position and rotating it in a direction in which hum pick-up is minimized usually eliminates this trouble.

(b) The monitoring vacuum tube voltmeter can, on occasions, feed a hum signal into the amplifier. This can be verified by disconnecting the VTVM altogether after it has served its purpose as a monitoring device for the signal generator voltage.

(c) Power lines below or above the test table, even if several yards away, have been recognized as major sources of magnetic hum-fields.

(d) Some generators are not equipped with suitable attenuators to put out signals of small amplitude. Quite often decade boxes, microvolters and other attenuators are then used in order to attenuate the output of the generator. Most of these attenuators represent large hum picking-up loops and on occasions they are not even electrostatically shielded. Therefore, they can be the cause of very large hum signals.

(e) On rare occasions leaky power transformers in either the generator or the scope can cause large hum currents in the common ground system.

(f) Poor ground connections between the amplifier and the scope or more so between the amplifier and the generator can create large hum signals.

After these preliminary tests have been carried out with the amplifier being switched to its 80 DB range, they should be repeated on other ranges having less gain, with correspondingly larger signals. Then, as operating conditions, reasonably free from hum-interference, have been established, the amplifier may now be used for the actual amplification of low-level signals in the microvolt region. To do this, the 100,000/1 test divider should be removed and the input lead should be plugged directly into the input terminals of the amplifier.

It is obvious that after the removal of the 100,000/1 test divider the amplifier is 100,000 times more sensitive against interference by hum-fields and radio frequency interference than before. Radio-interference hardly requires any special consideration as long as the 100,000/1 test divider is used because the divider is well shielded. Now, however, after removal of the divider this protection is no longer available and the input circuit must be shielded carefully against both hum and radio frequency interference. Careful shielding by conventional means, such as operation in a shielded room, mounting the test equipment which furnishes the AC signal to be observed in a shielded box, etc. will provide adequate protection. The user will soon become acquainted with the high susceptibility of the amplifier's input circuit to interference signals which is an unavoidable attribute to the extremely high sensitivity of the VS-64A amplifier.

Description of Circuit: Drawing VS-1067 shows the circuit diagram of the VS-64A amplifier.

The amplifiers consist of two cascaded 4-stage units, t 2, t 3, t 4, t 5, and t 6, t 7, t 8, and t 9. These units, one being the pre-amplifier and the other the main amplifier are interconnected by a 4-step output divider for the pre-amplifier, R28, R29, R30 and R31. In the maximum gain position (80 db) the full output of the pre-amplifier is transferred to the input of the main amplifier. In the 70 db position the output of the main amplifier is attenuated by 10 db, in the 60 db position by 20 db, and in the 50 position, by 30 db.

On the next four lower gain positions (40 db-10 db) the main amplifier is disconnected altogether, only the pre-amplifier being used. At 40 db the full output of the pre-amplifier is once more selected to be passed to the output terminals, at 30 db, 10 db less, at 20 db, 20 db less, and at 10 db, 30 db less. It will be noted that the output divider R28-R31 of the pre-amplifier has an additional resistor R32 in series which drops the actual signal voltage at the collector of output transistor $\mathfrak{t}$ 5 by more than 50%. This seeming waste of amplification is necessary in order to establish a de-coupling link between output transistor $\mathfrak{t}$ 5 of the pre-amplifier and input transistor $\mathfrak{t}$ 6 of the main amplifier when the instrument is operating in its 80 db position. Without such de-coupling an undesirable change of frequency response between the 80 db range and the other ranges would occur which is caused by the "echo-effect" due to transit, re-transit and re-re-transit of the signal in the collector junctions of the two transistors involved. This strange phenomenon is still being studied at present. The de-coupling system described has been found to be an effective counter-measure against this undesirable phenomenon.

The four transistors in each amplifier are directly coupled, which is particularly advantageous in a hushed transistor amplifier because the voltage drop across the collector junction in a transistor, operating in hushed condition, is essentially zero. In a hushed direct-coupled amplifier, it is therefore (contrary to direct-coupled vacuum tube amplifiers) not necessary to provide the customary "DC pedestals" for the emitter (or cathode) to make such direct coupling possible.

It will be noted that the first three emitters in each amplifier are directly interconnected while the fourth emitter has the customary resistor in the emitter circuit to provide the usual DC pedestal required for direct-coupling. The reason for this arrangement is that the first two transistors operate in hushed condition which means that, for instance, in the pre-amplifier the base and collector of $\tau 2$ and the base and collector of $\tau 3$ all have essentially the same potential to ground. It is in the general order of -150 mV. $\tau 4$ is not completely hushed and has a substantially higher collector voltage in the general order of -800 mV while $\tau 5$ is even less hushed, having a collector voltage in the general order of -2.8V.

While each of the two amplifiers is directly coupled within itself, both are in reality AC amplifiers having capacitive input and output coupling and being equipped with a powerful DC feedback circuit (R13 and R6 in the pre-amplifier and R25 and R19 in the main amplifier). The DC feedback is taken from the emitter of the output transistor and is fed into the base of the input transistor. Since signals are in phase-opposition at these two points a vigorous DC self-biasing action is produced which counteracts effectively bias-drifts liable to occur as the result of room temperature changes. Each DC feedback path has a by-pass condenser (C3 in the pre-amplifier and C12 in the main amplifier) which absorbs the AC component of the output signal thereby preventing negative feedback of the AC output signal into the base of the input transistor.

A second feedback loop handling both AC and DC signals and serving the dual purpose of gain stabilization and bandpass extension is provided by the

common emitter resistor for the first three transistors in each amplifier (R9 in the pre-amplifier and R21 in the main amplifier). Each of these common emitter resistors, in reality, acts in two different ways. Due to phase-inversion between subsequent stages, the common emitter resistor has a slight regenerative effect between neighbor-transistors, for instance, between τ 2 and τ 3 or τ 3 and τ 4, but it has an overruling degenerative effect upon the first three stages together. The local regenerative effect described raises local stage gain and therefore indirectly increases the overall degeneration since the latter is directly proportional to local stage gain. The gain of the fourt transistor (τ 5 in the pre-amplifier and τ 9 in the main amplifier) is stabilized by the large emitter resistor in that stage.

Each amplifier is equipped with frequency-response correcting networks. They prevent an undesirable rise of gain near the upper cut-off point of the pass-band due to phase rotation. Trimmer C14 and adjustable control R10 provide both an amplitude reduction and phase correction in the region of the bandpass in which such an undesirable rise would otherwise occur. Trimmer C4 and fixed condenser C5 serve a similar purpose. The main amplifier has equivalent trimmers and controls in the corresponding sections of its circuit. The two trimmers and the control in each amplifier are carefully adjusted in each instrument to give the desired frequency response before the VS-64A amplifier is shipped. They normally do not require resetting and should be touched only if, after a change of transistors, particularly input transistors, this should be found to be necessary. When

making such an adjustment, the bandpass controls should be set for full bandwidth (2 cps - 180 KC). The main amplifier should be adjusted so that its response is flat within 0.5 db up to 180 KC, while the pre-amplifier should be adjusted to have a 3 db fall-off at 180 KC when both amplifiers are cascaded (50-80 db).

Each amplifier is also equipped with a DC centering control (R 4 in the pre-amplifier and R16 in the main amplifier). It supplies an adjustable bias current into the base of the input transistor of each amplifier and should be set for -2.8V DC at the collector of the output transistor (t 5 in the pre-amplifier and t 9 in the main amplifier). Proper setting of this voltage is important to avoid overloading or clipping of either amplifier, particularly on the 50 db and on the 10 db ranges. The collector voltage should be measured with a vacuum tube voltmeter. It can also be adjusted by observing the behavior of the amplifier on either the 50 db or the 10 db range, preferably on both, the adjustment being made in such manner that nearly symmetrical clipping occurs on the upper and lower crest of a low frequency sine wave (such as 400 cps) being fed into amplifier.

The pre-amplifier chassis has an additional transistor t 1 which is an emitter-follower. Its performance resembles the customary cathode-follower in a vacuum tube amplifier except that its conversion efficiency is substantially higher than in the conventional cathode-follower. The emitter-follower is used only when the amplifier is switched to its 100 K input impedance position. In this position the

signal passes first into the emitter follower and then into the pre-amplifier, the emitter follower having a 98 to 99% voltage conversion efficiency, its input impedance being approximately 100K and its dynamic output impedance usually being below 200 ohm.

The emitter follower is not hushed since it has a collector junction voltage in the order of 3 V. However, the high noise developed in its collector junction is nearly completely being de-amplified in the transistor itself in view of its high conversion efficiency, in other words, since by itself it possesses a feedback ratio in the order of 40 db. The small remainder of noise which is being passed on to the subsequent pre-amplifier causes the VS-64A amplifier to be slightly more noisy when used with 100 K input impedance. However, there are many applications in which the higher noise will be preferred in view of the higher input impedance than the lower noise in the 10 K position where input impedance is smaller.

The VS-64A amplifier is equipped with two bandpass filters, one limiting the upper end of the frequency response and the other the lower end. These two filters are located near the output terminals of the circuit and consist of simple R/C networks. Each filter is followed by an emitter follower, t10 and t11, which act as impedance converters to prevent undesirable inter-action between the two filters. Emitter follower t12, also functions as an impedance converter to reduce the shunting effect the filters have upon the range attenuator.

Power is supplied to the instrument from two parallel 6V batteries (Burgess FP1) which have a minimum life of 150 hours and should be replaced as soon as the monitoring voltmeter on the panel indicates a voltage lower than 5.4. The monitoring voltmeter also replaces the customary pilot light in this amplifier which is not being provided since it would draw more power than the total of 10 transistors and would shorten battery life unnecessarily.

GUARANTEE

THE VS-64A AMPLIFIER IS GUARANTEED BY US FOR A PERIOD OF ONE YEAR FROM THE DATE OF SHIPMENT AGAINST DEFECTIVE COMPONENTS AND FAULTY WORKMANSHIP.

EXCLUDED IN THIS GUARANTEE ARE ALL DEFECTS CAUSED BY ABUSE OF THE AMPLIFIER, PARTICULARLY SUCH ABUSE WHICH RESULTS IN BURNING OUT OF TRANSISTORS. WITH PROPER HANDLING, REPLACEMENT OF TRANSISTORS IS UNNECESSARY FOR MANY YEARS.

IF AN AMPLIFIER SHOULD BE CONSIDERED TO BE DEFECTIVE, IT SHOULD NOT BE SENT IN TO US FOR REPAIR WITHOUT WRITTEN AUTHORIZATION. PLEASE STATE IN YOUR REPORT THE NATURE OF THE COMPLAINT AND WHETHER ANY COMPONENTS IN THE INSTRUMENT HAVE BEEN REPLACED IN AN EFFORT TO CORRECT THE TROUBLE.

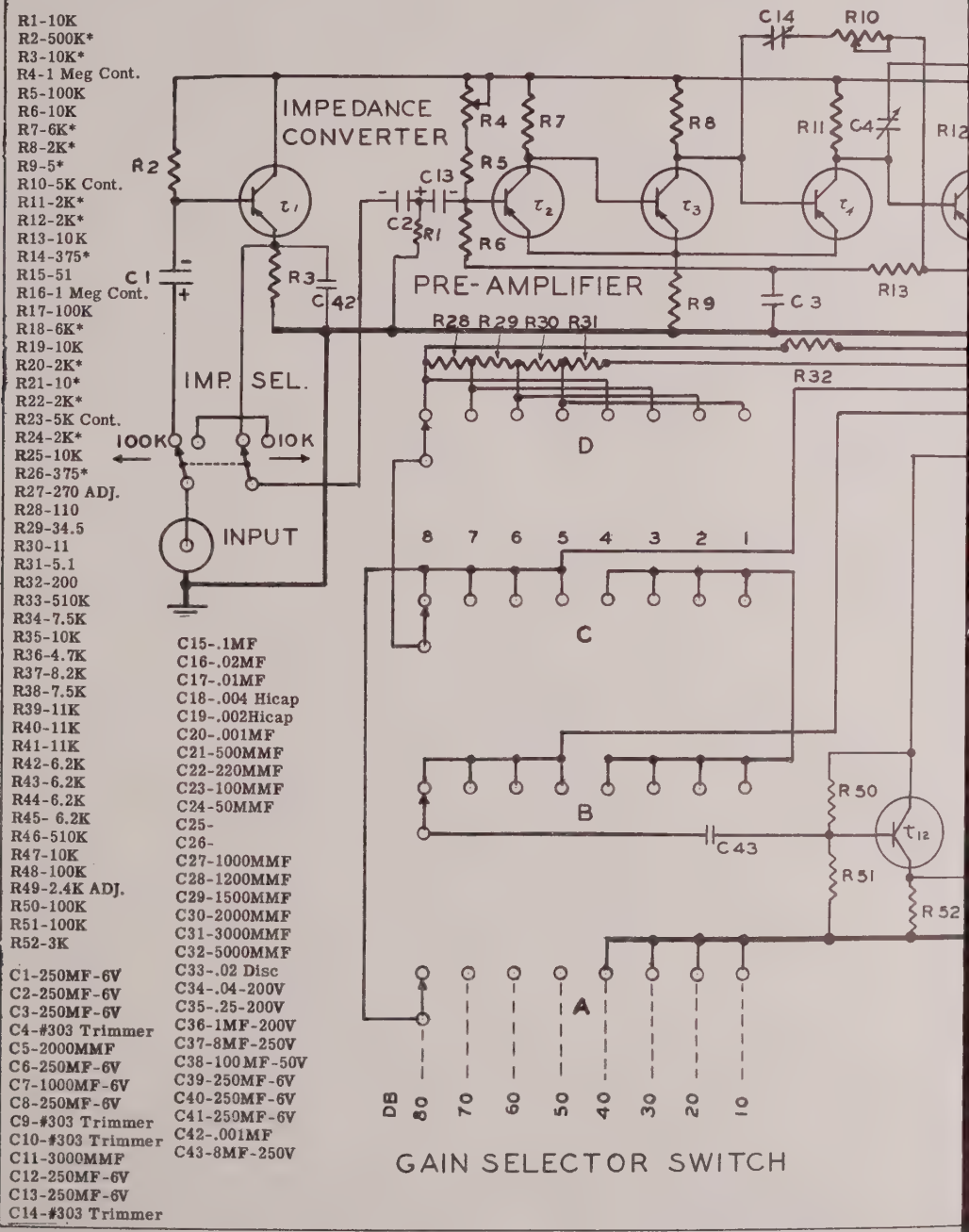
TWO-WAY TRANSPORTATION CHARGES ARE TO BE BORNE BY THE CUSTOMER.

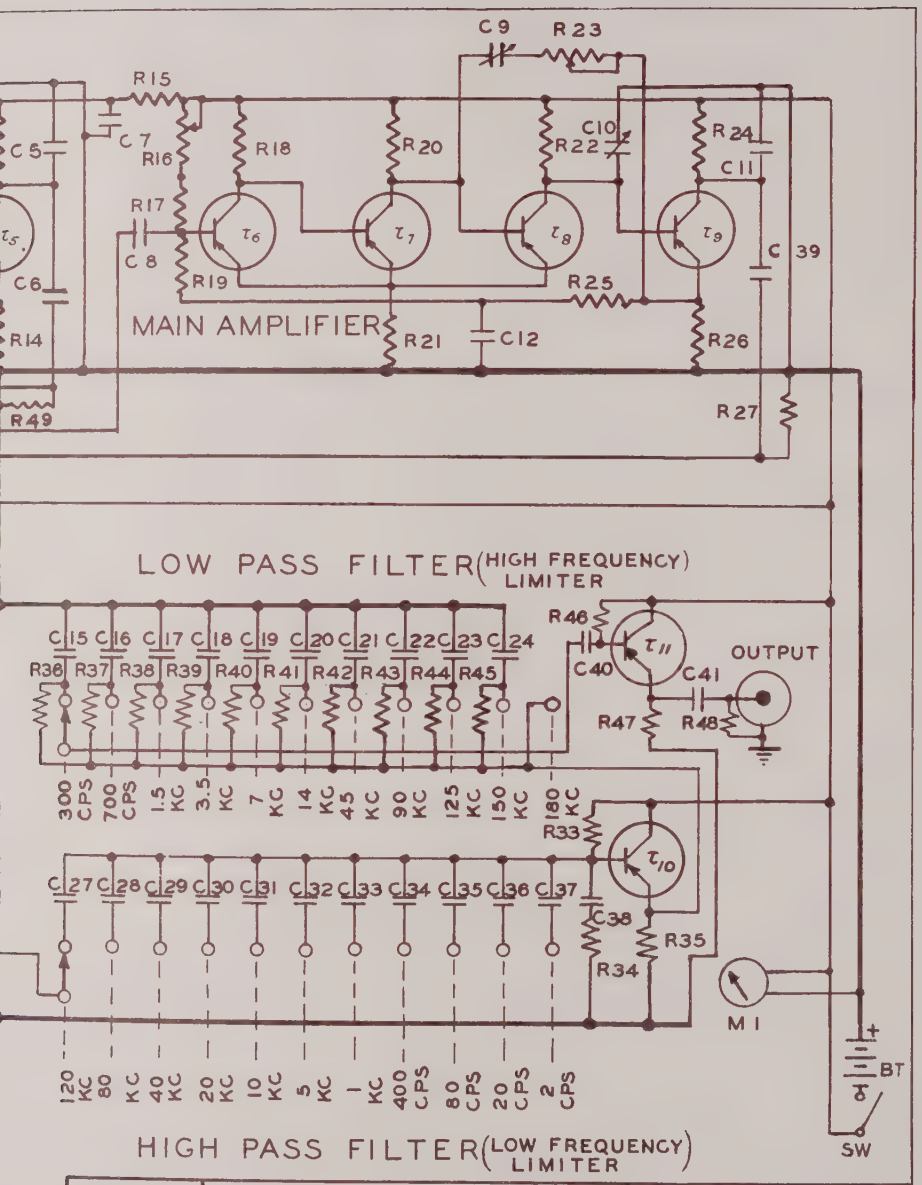
MILLIVAC INSTRUMENTS DIVISION
COHU ELECTRONICS, INC.
SCHENECTADY, NEW YORK

R1-10K
R2-500K*
R3-10K*
R4-1 Meg Cont.
R5-100K
R6-10K
R7-6K*
R8-2K*
R9-5*
R10-5K Cont.
R11-2K*
R12-2K*
R13-10K
R14-375*
R15-51
R16-1 Meg Cont.
R17-100K
R18-6K*
R19-10K
R20-2K*
R21-10*
R22-2K*
R23-5K Cont.
R24-2K*
R25-10K
R26-375*
R27-270 ADJ.
R28-110
R29-34.5
R30-11
R31-5.1
R32-200
R33-510K
R34-7.5K
R35-10K
R36-4.7K
R37-8.2K
R38-7.5K
R39-11K
R40-11K
R41-11K
R42-6.2K
R43-6.2K
R44-6.2K
R45- 6.2K
R46-510K
R47-10K
R48-100K
R49-2.4K ADJ.
R50-100K
R51-100K
R52-3K

C1-250MF-6V
C2-250MF-6V
C3-250MF-6V
C4-#303 Trimmer
C5-2000MMF
C6-250MF-6V
C7-1000MF-6V
C8-250MF-6V
C9-#303 Trimmer
C10-#303 Trimmer
C11-3000MMF
C12-250MF-6V
C13-250MF-6V
C14-#303 Trimmer

C15-.1MF
C16-.02MF
C17-.01MF
C18-.004 Hicap
C19-.002Hicap
C20-.001MF
C21-500MMF
C22-220MMF
C23-100MMF
C24-50MMF
C25-
C26-
C27-1000MMF
C28-1200MMF
C29-1500MMF
C30-2000MMF
C31-3000MMF
C32-5000MMF
C33-.02 Disc
C34-.04-200V
C35-.25-200V
C36-1MF-200V
C37-8MF-250V
C38-100MF-50V
C39-250MF-6V
C40-250MF-6V
C41-250MF-6V
C42-.001MF
C43-8MF-250V





DWG. NO. VS-1067	TYPE VS-64 A HUSHED TRANSISTOR PRE-AMPLIFIER	DRAWN 9-25-60
DATE MAR 5, 1956	VOLKERS & SCHAFFER MFG. CORP.	ED. 3 AFTER SER. 85

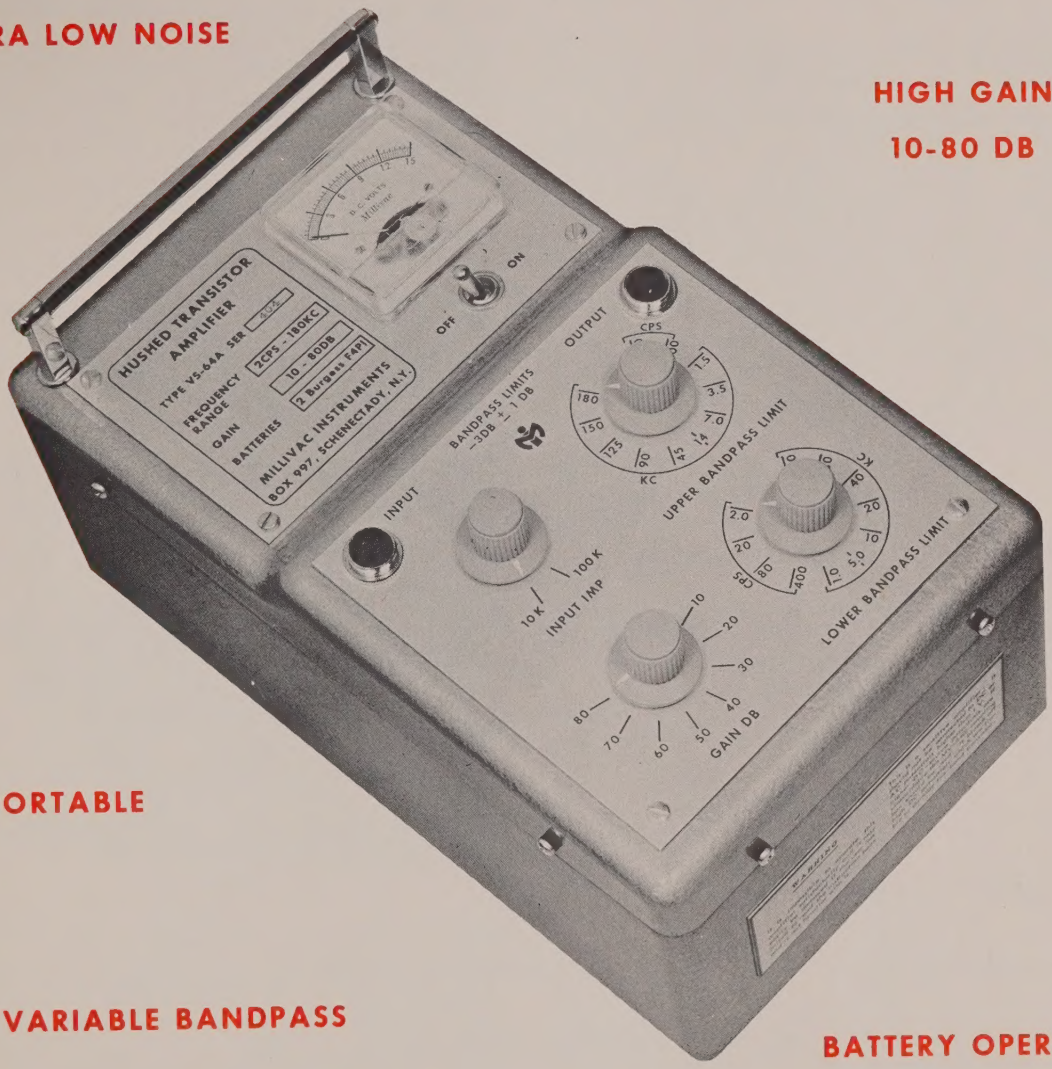
MILLIVAC INSTRUMENTS

TYPE VS-64A

Hushed Transistor AC Amplifier

ULTRA LOW NOISE

HIGH GAIN
10-80 DB



PORTABLE

VARIABLE BANDPASS

BATTERY OPERATED

NOISE REDUCTION IN TRANSISTOR AMPLIFIERS

Hushed transistors operate with essentially zero or reversed collector junction voltage. Thus, the carrier accelerating field which is normally produced by collector potential is practically eliminated or reversed which causes transit time to be lengthened and results in a more effective dispersion of carriers and a corresponding reduction of shot noise. The noise voltage of a hushed transistor, referred to its shorted input circuit, is therefore 20 - 30 db lower than the noise voltage of most shorted vacuum tubes.

DESCRIPTION OF VS-64A AMPLIFIER

The VS-64A Ultra-Low-Noise AC Pre-Amplifier contains many improvements over earlier hushed transistor amplifiers.

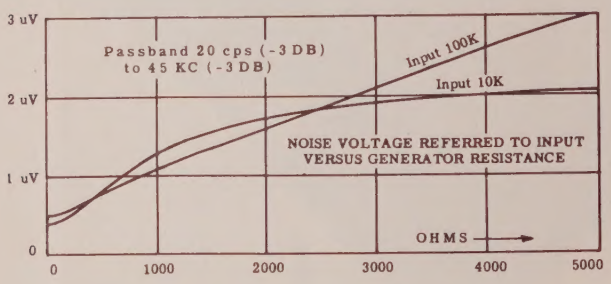
By equipping the VS-64A amplifier with high quality precision resistors, "extra noise" beyond pure thermal noise could be reduced still further below the already unusually low 0.5 uV RMS noise voltage within a 60 KC pass-band, which our earlier models had. Two band-pass limiting

switches make it possible to restrict noise still further by eliminating its components, associated with an unwanted extension of the pass-band above or below the desired frequency range. The following tables show typical noise voltages referred to the shorted input with either the high frequency or

UPPER FREQ. LIMIT		LOWER FREQ. LIMIT	
FREQUENCY	E NOISE INPUT SHORTED	FREQUENCY	E NOISE INPUT SHORTED
300 CPS	50×10^{-9} V	120 KC	350×10^{-9} V
700 CPS	62	80 KC	455
1.5 KC	75	40 KC	535
3.5 KC	98	20 KC	560
7 KC	125	10 KC	570
14 KC	155	5 KC	580
45 KC	300	1 KC	590
90 KC	445	400 CPS	600
125 KC	520	80 CPS	605
150 KC	555	20 CPS	615
180 KC	615	2 CPS	695
WITH LOWER LIMIT 20 CPS		WITH UPPER LIMIT 180 KC	

the low frequency limiting switches in their various positions. They show that with a substantially restricted pass-band, noise voltages as low as 100 muV or lower can be expected.

Noise voltage, referred to the input terminals, increases with source impedance. The relationship is shown in the two curves plotted below for 10 K and 100 K input impedance.

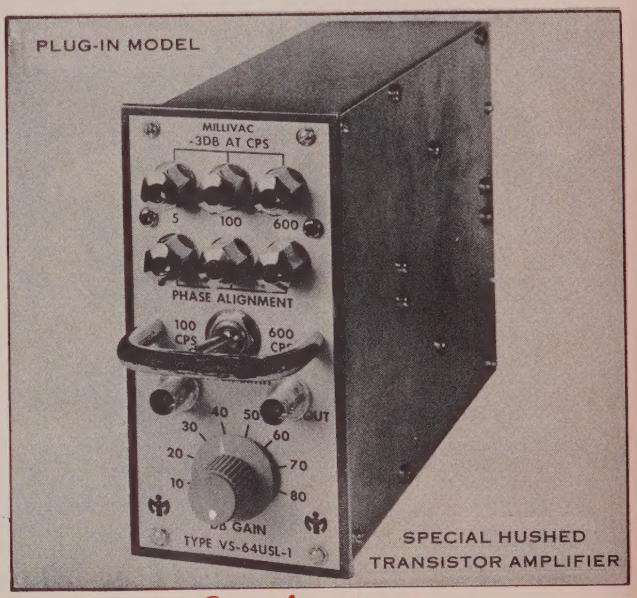


The gain of the VS-64A amplifier is adjustable in steps from 10 db to 80 db. This makes the amplifier a highly flexible laboratory instrument which can be used to increase the sensitivity of oscilloscopes or vacuum tube voltmeters, not only in cases where extreme sensitivity is desired but also if only a moderate sensitivity boost of 10 or 20 db is needed.

The input impedance of the VS-64A is adjustable in two steps, either 10 k or 100 k. With 10 k input impedance, the signal is fed directly into the base of the input transistor while in the 100k position of the input impedance selector switch it is fed into the base of an emitter - follower (impedance converter). The emitter - follower increases noise slightly as shown in the more detailed specifications on the right.

MODIFIED VERSIONS

Although the present design of the VS-64A amplifier, which incorporates a high total gain (80 db), selection of gain, band pass controls and choice of two input impedances, in accordance with carefully established majority requirements, our customers have, on occasions, asked us to design and manufacture for them special modifications of this amplifier. We have supplied modified VS-64A amplifiers with higher input impedance, also with 40 db gain, with special band pass selector switches and plug-in models without internal batteries for use in system modules (see illustration below). Also, careful study of our other literature describing high-impedance, low-noise amplifiers is recommended.



Specifications

GAIN: 10 - 80 DB, plus/minus 1 DB, selectable in 10 DB steps.

FREQUENCY RESPONSE (including capacitive loading by amplifier's own shielded output lead, but exclusive additional capacitive loading): 3 DB down at 2 cps and 180 KC. - Amplifier has upper and lower bandpass limiting switches, each 11 positions, limiting frequency response as follows (-3 DB, with 1 DB tol.): Upper limits 180 KC, 150 KC, 125 KC, 90 KC, 45 KC, 15 KC, 7 KC, 3.5 KC, 1.5 KC, 700 cps and 300 cps, lower limits 2 cps, 20 cps, 80 cps, 400 cps, 1 KC, 5 KC, 10 KC, 20 KC, 40 KC, 80 KC and 120 KC (allow 10% tolerance, all frequencies).

IMPUT IMPEDANCE: selectable in 2 steps, 10 K or 100 K, the latter increasing noise with shorted input slightly.

OUTPUT IMPEDANCE: approx. 2 K.

DYNAMIC RANGE: maximum input on 10, 20, 30, 40 DB ranges 1 mV RMS, 50, 60, 70 and 80 DB ranges 10 uV RMS. These limits provide sufficient output on the 30, 40, 70 and 80 DB ranges to drive practically all modern scopes to full screen deflection (100 mV peak-to-peak full screen). On the 10, 20, 50 and 60 DB ranges higher scope sensitivity or VTVM post-amplifiers are required.

NOISE (with input shorted, 10 K input position): less than 450 muV RMS over a 60 KC pass-band, more with wider pass-band and less with lower pass-band. For relation between noise and pass-band see table in description, above. Noise voltage will not be more than 1.5 DB in excess of figures given in table above. Noise Figure at 1 KC with optimum generator resistance (usually between 1 K and 2 K) 3 DB, tolerance plus/minus 1 DB (with 100 K input impedance).

DISTORTION (other than noise): 1% max. at 50 mV peak-to-peak output level, 2.5% max. at 100 mV level.

BATTERIES: 2 Burgess F4P1, minimum life 150 hrs.

ACCESSORIES: shielded input and output leads, 1000:1 ratio Input Test Divider (10 K/10 ohms, 3% tolerance).

DIMENSIONS: 7" wide, 12" deep, 5" high, including prop-up rail for scopes.

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